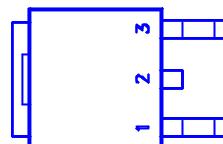
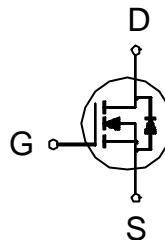


**NIKO-SEM**
**N-Channel Logic Level Enhancement  
Mode Field Effect Transistor**
**P3056LDG**  
**TO-252 (DPAK)**  
**Lead-Free**
**PRODUCT SUMMARY**

$V_{(BR)DSS}$	$R_{DS(ON)}$	$I_D$
25	50m	12A



1. GATE
- 
2. DRAIN
- 
3. SOURCE

**ABSOLUTE MAXIMUM RATINGS ( $T_c = 25^\circ\text{C}$  Unless Otherwise Noted)**

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Gate-Source Voltage		$V_{GS}$	$\pm 12$	V
Continuous Drain Current	$T_c = 25^\circ\text{C}$	$I_D$	12	A
	$T_c = 100^\circ\text{C}$		8	
Pulsed Drain Current <sup>1</sup>		$I_{DM}$	45	
Avalanche Energy	$L = 0.1\text{mH}$	$E_{AS}$	60	mJ
Repetitive Avalanche Energy <sup>2</sup>	$L = 0.05\text{mH}$	$E_{AR}$	3	
Power Dissipation	$T_c = 25^\circ\text{C}$	$P_D$	48	W
	$T_c = 100^\circ\text{C}$		20	
Operating Junction & Storage Temperature Range		$T_j, T_{stg}$	-55 to 150	°C
Lead Temperature (1/16" from case for 10 sec.)		$T_L$	275	

**THERMAL RESISTANCE RATINGS**

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Case	$R_{\theta JC}$	1	3	°C / W
Junction-to-Ambient	$R_{\theta JA}$		75	
Case-to-Heatsink	$R_{\theta CS}$			

<sup>1</sup>Pulse width limited by maximum junction temperature.<sup>2</sup>Duty cycle ≤ 1%**ELECTRICAL CHARACTERISTICS ( $T_c = 25^\circ\text{C}$ , Unless Otherwise Noted)**

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
<b>STATIC</b>						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$	25			V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	0.5	0.7	1.0	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\text{V}, V_{GS} = \pm 12\text{V}$			$\pm 250$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}$			25	$\mu\text{A}$
		$V_{DS} = 20\text{V}, V_{GS} = 0\text{V}, T_j = 125^\circ\text{C}$			250	

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On-State Drain Current <sup>1</sup>	I <sub>D(ON)</sub>	V <sub>DS</sub> = 10V, V <sub>GS</sub> = 10V	12			A
Drain-Source On-State Resistance <sup>1</sup>	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 5V, I <sub>D</sub> = 12A		70	120	m
		V <sub>GS</sub> = 10V, I <sub>D</sub> = 12A		50	90	
Forward Transconductance <sup>1</sup>	g <sub>f</sub>	V <sub>DS</sub> = 15V, I <sub>D</sub> = 12A		16		S
<b>DYNAMIC</b>						
Input Capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 15V, f = 1MHz		450		pF
Output Capacitance	C <sub>oss</sub>			200		
Reverse Transfer Capacitance	C <sub>rss</sub>			60		
Total Gate Charge <sup>2</sup>	Q <sub>g</sub>	V <sub>DS</sub> = 0.5V <sub>(BR)DSS</sub> , V <sub>GS</sub> = 10V, I <sub>D</sub> = 6A		15		nC
Gate-Source Charge <sup>2</sup>	Q <sub>gs</sub>			2.0		
Gate-Drain Charge <sup>2</sup>	Q <sub>gd</sub>			7.0		
Turn-On Delay Time <sup>2</sup>	t <sub>d(on)</sub>	V <sub>DS</sub> = 15V, R <sub>L</sub> = 1 I <sub>D</sub> ≈ 12A, V <sub>GS</sub> = 10V, R <sub>GS</sub> = 2.5		6.0		nS
Rise Time <sup>2</sup>	t <sub>r</sub>			6.0		
Turn-Off Delay Time <sup>2</sup>	t <sub>d(off)</sub>			20		
Fall Time <sup>2</sup>	t <sub>f</sub>			5.0		
<b>SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (T<sub>C</sub> = 25 °C)</b>						
Continuous Current	I <sub>S</sub>	I <sub>F</sub> = I <sub>S</sub> , V <sub>GS</sub> = 0V			12	A
Pulsed Current <sup>3</sup>	I <sub>SM</sub>				20	
Forward Voltage <sup>1</sup>	V <sub>SD</sub>				1.5	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = I <sub>S</sub> , dI <sub>F</sub> /dt = 100A / μS		30		nS
Peak Reverse Recovery Current	I <sub>RM(REC)</sub>			15		A
Reverse Recovery Charge	Q <sub>rr</sub>			0.043		μC

<sup>1</sup>Pulse test : Pulse Width ≤ 300 μsec, Duty Cycle ≤ 2%.<sup>2</sup>Independent of operating temperature.<sup>3</sup>Pulse width limited by maximum junction temperature.**REMARK: THE PRODUCT MARKED WITH “P3056LDG”, DATE CODE or LOT #**

Orders for parts with Lead-Free plating can be placed using the PXXXXXXG parts name.

**NIKO-SEM****N-Channel Logic Level Enhancement  
Mode Field Effect Transistor****P3056LDG  
TO-252 (DPAK)  
Lead-Free****TO-252 (DPAK) MECHANICAL DATA**

Dimension	mm			Dimension	mm		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	9.35		10.4	H	0.89		2.03
B	2.2		2.4	I	6.35		6.80
C	0.45		0.6	J	5.2		5.5
D	0.89		1.5	K	0.6		1
E	0.45		0.69	L	0.5		0.9
F	0.03		0.23	M	3.96	4.57	5.18
G	5.2		6.2	N			

